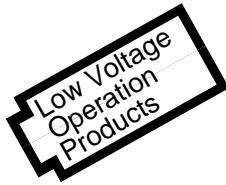


SCI7661C_{0A}/M_{0A}

DC-DC Converter



- 95% Typical Power Efficiency
- Doubled or Tripled Output Voltage
- Internal Voltage Regulator

DESCRIPTION

The SCI7661C_{0A}/M_{0A} CMOS DC-DC Converter features high operational performance with low power dissipation. It consists of two major parts: the booster circuitry and the regulator circuitry. The booster generates a doubled output voltage (–2.4 to –12V) or tripled output voltage (–3.6 to –18V) from the input (–1.2 to –6V). The regulator is capable of setting the output to any desired voltage. The regulated voltage can be given one of the three threshold temperature gradients.

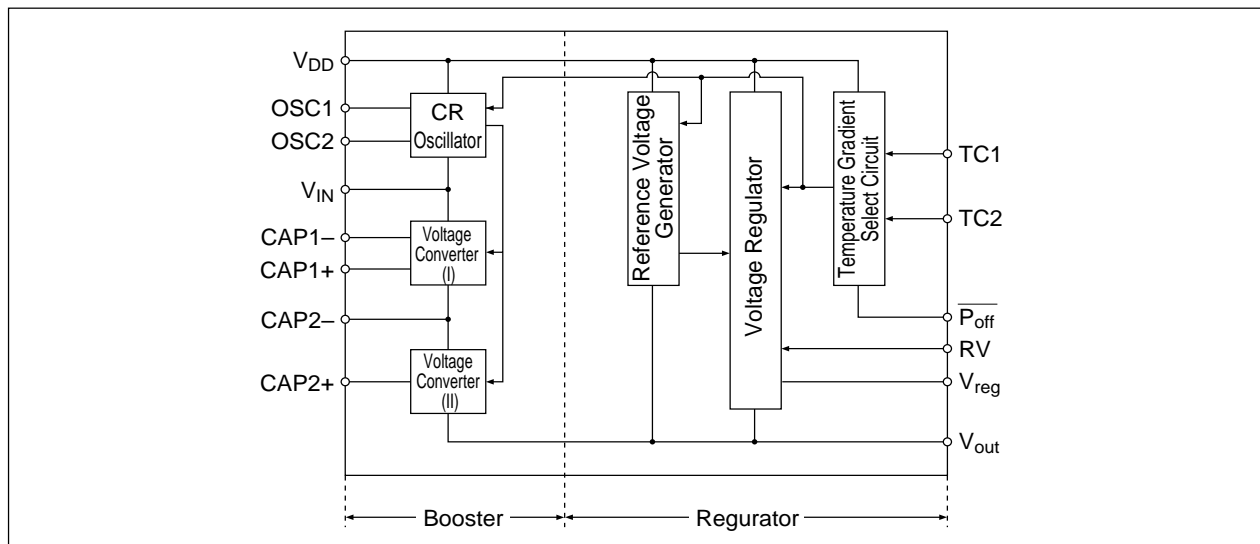
FEATURES

- High performance with low power dissipation
- Simple conversion of V_{IN} (–5V) to $|V_{IN}|$ (+5V), $2|V_{IN}|$ (+10V), $2V_{IN}$ (–10V) or $3V_{IN}$ (–15V)
- On-chip output voltage regulator
- Power conversion efficiency–Typ. 95%
- Temperature gradient for LCD power supply – 0.1% / °C, 0.4%/°C or 0.6% / °C
- Power off by external signals – Stationary current at power off – Max. 2 μ A
- Cascade connection–two device connected:

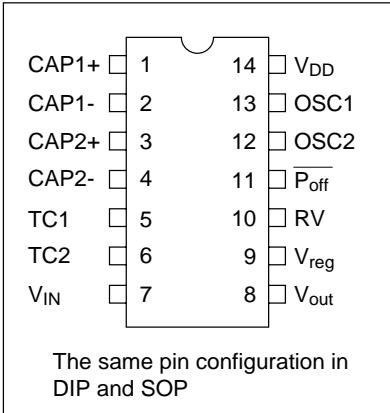
V_{IN} = –5V, V_{OUT} = –20V

- On-chip C'–R oscillator
- Package SCI7661C_{0A}: DIP-14pin(plastic)
SCI7661M_{0A}: SOP5-14pin(plastic)
SCI7661M_{AA}: SSOP2-16pin(plastic)

BLOCK DIAGRAM



■ PIN CONFIGURATION



■ PIN DESCRIPTION

Pin name	No.	Function
CAP1+, CAP1-	1, 2	Terminal for connection of capacitor for doubler
CAP2+, CAP2-	3, 4	Terminal for connection of capacitor for tripler
TC1, TC2	5, 6	Temperature gradient selection terminal
V _{IN}	7	Power supply terminal(negative, system supply GND)
V _{OUT}	8	Output terminal at tripling
V _{reg}	9	Regulated voltage output terminal
R _V	10	Regulated voltage control terminal
P _{off}	11	V _{reg} output ON/OFF control terminal
OSC2, OSC1	12, 13	Oscillation resistor connection terminal
V _{DD}	14	Power supply terminal(positive system supply VCC)

■ ABSOLUTE MAXIMUM RATINGS

(V_{DD}=0V)

Rating	Symbol	Min.	Max.	Unit	Remark
Input supply voltage	V _I	-20/N	0.5	V	N=2 : Doubler N=3 : Tripler
Input terminal voltage	V _I	V _{IN} -0.5	0.5	V	OSC1, P _{off}
		V _{OUT} -0.5	0.5	V	TC1, TC2, RV
Output voltage	V _O	-20.0		V	
Allowable loss	P _d		300	mW	
Operating temperature	T _{opr}	-30	85	°C	Plastic package
Storage temperature	T _{stg}	-55	150	°C	
Soldering temperature and time	T _{sol}	260°C, 10s(at lead)		-	

Note: When this IC is soldered in the solder-reflow process, be sure to maintain the reflow furnace at the curve shown in "Fig. 1-5 Reflow Furnace Temperature Curve" of this DATA BOOK. And this IC can not be exposed to high temperature of the solder dipping.

■ ELECTRICAL CHARACTERISTICS

(V_{DD} = 0V, V_{IN}=-5V, T_a=-30 to 85°C)

Characteristic	Symbol	Min.	Typ.	Max.	Unit	Condition
Input supply voltage	V _I	-6.0		-1.2	V	
Output voltage	V _O	-18.0			V	
	V _{reg}	-18		-2.6	V	R _L =∞, R _{RV} =1MΩ, V _O =-18V
Regulator operating voltage	V _{OUT}	-18.0		-3.2	V	
Booster current consumption	I _{opr1}		60	100	μA	R _L =∞, R _{OSC} =1MΩ
Regulator current consumption	I _{opr2}		50	12.0	μA	R _L =∞, R _{RV} =1MΩ V _{OUT} =-15V
Stationary current	I _Q			2.0	μA	TC2=TC1=V _{OUT} , R _L =∞
Oscillation frequency	f _{osc}	16	20	24	kHz	R _{OSC} =1MΩ
Output impedance	R _{OUT}		150	200	Ω	I _{OUT} =10mA
Booster power conversion efficiency	P _{eff}	90	95		%	I _{OUT} =5mA
Regulated output voltage fluctuation	$\frac{\Delta V_{reg}}{\Delta V_{OUT} \cdot V_{reg}}$		0.2		%/V	-18V < V _{OUT} < -8V, V _{reg} =-8V, R _L =∞, T _a =25°C

PERFORMANCE CURVES

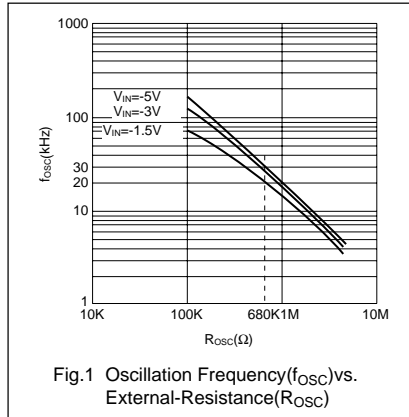


Fig. 1 Oscillation Frequency(f_{osc})vs. External-Resistance(R_{osc})

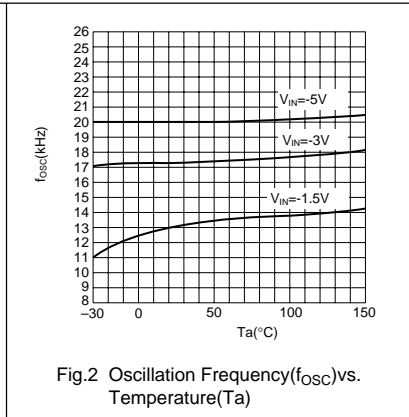


Fig. 2 Oscillation Frequency(f_{osc})vs. Temperature(T_a)

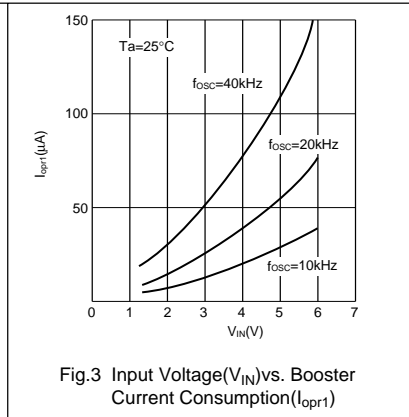


Fig. 3 Input Voltage(V_{IN})vs. Booster Current Consumption(I_{opp1})

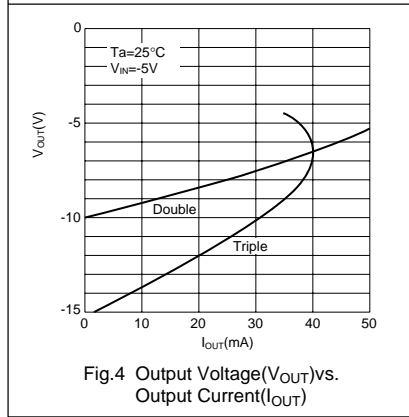


Fig. 4 Output Voltage(V_{OUT})vs. Output Current(I_{OUT})

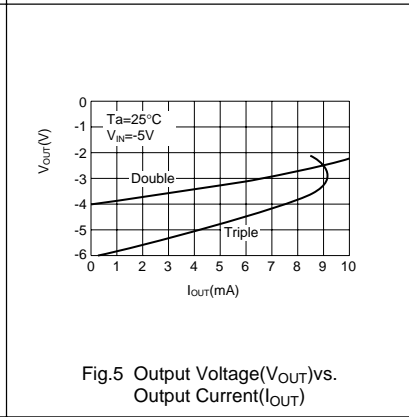


Fig. 5 Output Voltage(V_{OUT})vs. Output Current(I_{OUT})

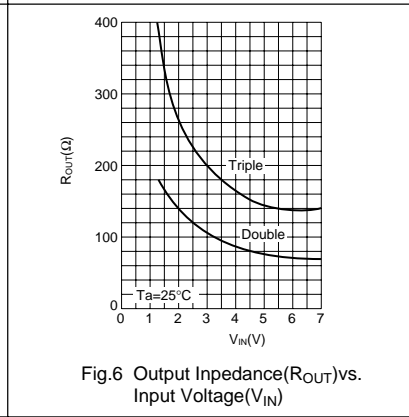


Fig. 6 Output Impedance(R_{OUT})vs. Input Voltage(V_{IN})

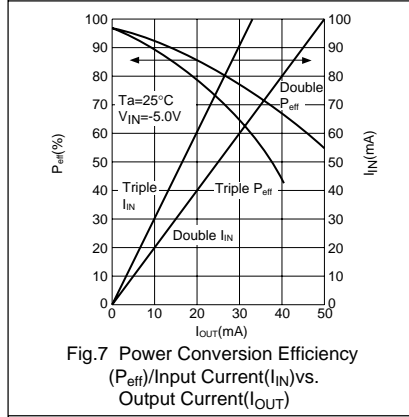


Fig. 7 Power Conversion Efficiency (P_{eff})/Input Current(I_{IN})vs. Output Current(I_{OUT})

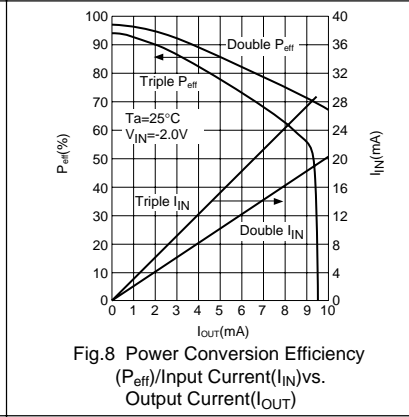


Fig. 8 Power Conversion Efficiency (P_{eff})/Input Current(I_{IN})vs. Output Current(I_{OUT})

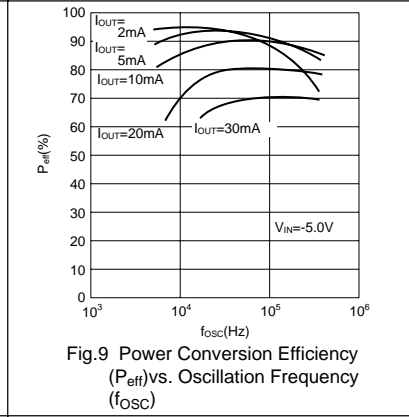


Fig. 9 Power Conversion Efficiency (P_{eff})vs. Oscillation Frequency (f_{osc})

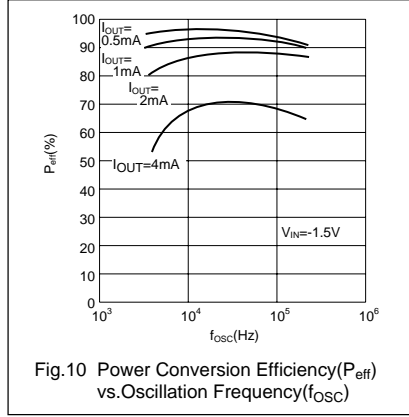


Fig. 10 Power Conversion Efficiency(P_{eff}) vs. Oscillation Frequency(f_{osc})

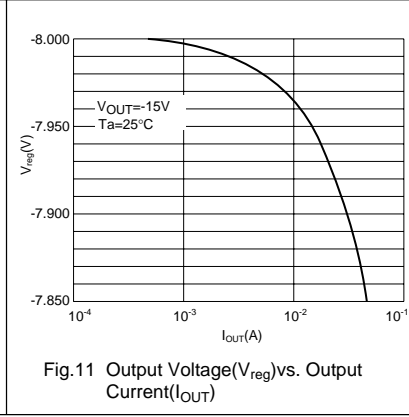


Fig. 11 Output Voltage(V_{reg})vs. Output Current(I_{OUT})

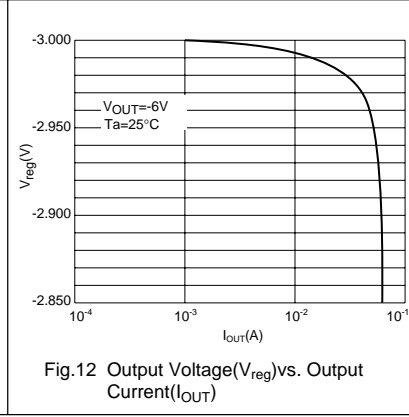
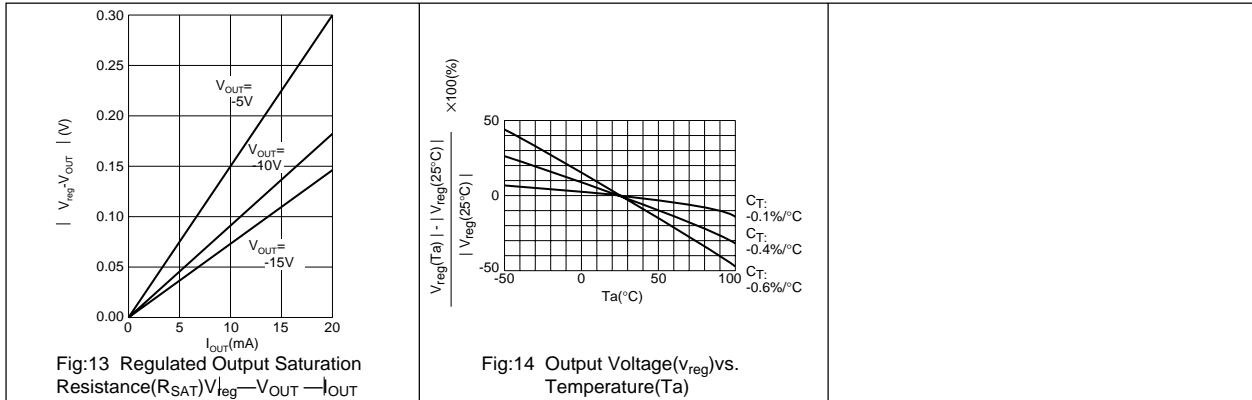


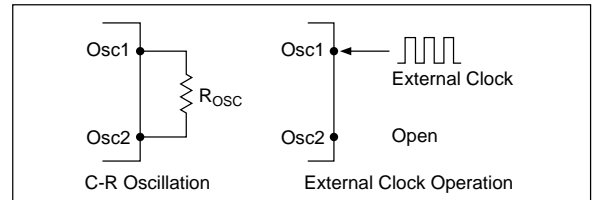
Fig. 12 Output Voltage(V_{reg})vs. Output Current(I_{OUT})



CIRCUIT DESCRIPTION

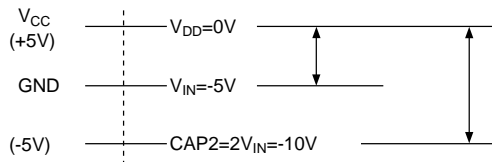
C-R Oscillator

The SCI7661C/M contains a C-R oscillator for internal oscillation. It consists of an external resistor R_{osc} connected between the OSC1 pin and OSC2 pin.

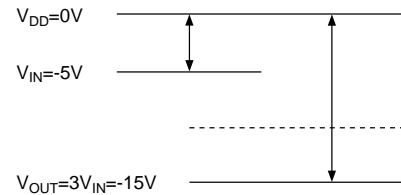


Voltage Converters

The voltage converters double/triple the input supply voltage (V_{in}) using clocks generated by the C-R oscillator



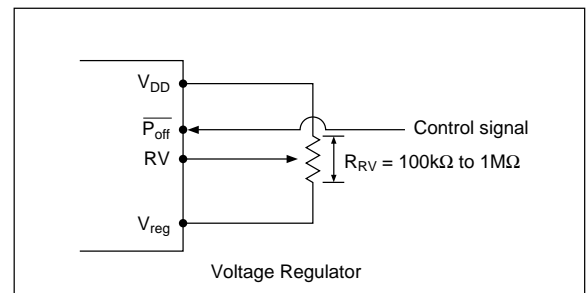
Typical Doubled Voltage Relations



Typical Tripled Voltage Relations

Reference Voltage Generator and Voltage Regulator

The reference voltage generator produces reference voltage needed for operation of regulator circuit. The voltage regulator is used to regulate a boosted output voltage and its circuit contains a power-off function which uses signals from the system for on-off control of the V_{reg} output.



Temperature Gradient Selector Circuit

The SCI7661C/M provides the V_{reg} output with a temperature gradient suitable for LCD driving.

● Temperature Gradient Assignment

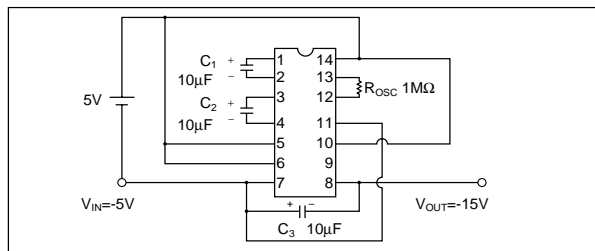
$\overline{P_{off}}$	TC2	TC1	Temp. Gradient	V_{reg} Output	CR oscillation	Remarks
1 (V_{DD})	L (V_{OUT})	L (V_{OUT})	-0.4%/°C	ON	ON	Cascade connection
1	L	H (V_{DD})	-0.1%/°C	ON	ON	
1	H (V_{DD})	L	-0.6%/°C	ON	ON	
1	H	H	-0.6%/°C	ON	OFF	
0 (V_{IN})	L	L	-	OFF (Hi-Z)	OFF	
0	L	H	-	OFF (Hi-Z)	OFF	Without regulation
0	H	L	-	OFF (Hi-Z)	OFF	
0	H	H	-	OFF (Hi-Z)	ON	

NOTE: The potential at Low level is different between the $\overline{P_{off}}$ pin and the TC1/TC2 pin.

■ BASIC EXTERNAL CONNECTION

● Voltage Doubler and Tripler

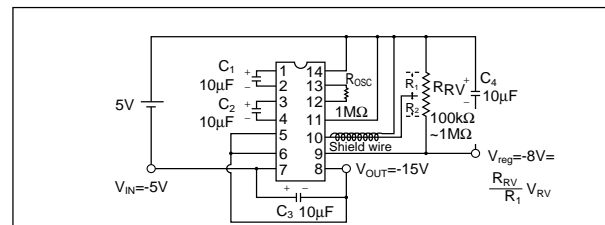
A doubled voltage can be obtained at V_{OUT} (CAP2-) by disconnecting capacitor C_2 from the tripler configuration and shorting CAP2- (pin4) and V_{OUT} (pin 8).



Voltage Tripler

● Voltage Tripler+Regulator

V_{reg} output is given a temperature gradient, after boosted output V_{OUT} regulated. In this connection, both V_{OUT} and V_{reg} can be taken out at the same time.

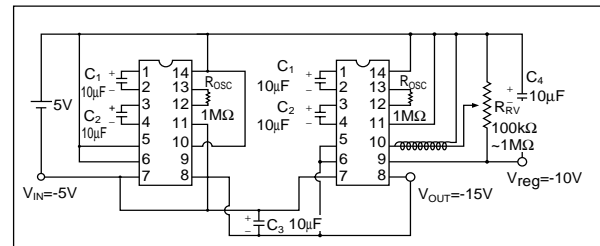


Tripler+Regulator
(-0.4%/°C selected as temperature gradient)

● Parallel Connection

Parallel connection of n circuits can reduce R_{OUT} to about $1/n$, that output impedance R_{OUT} can be reduced by connecting serial configuraiton. A single smoothing capacitor C_3 can be used commonly for all parallelly connected circuit.

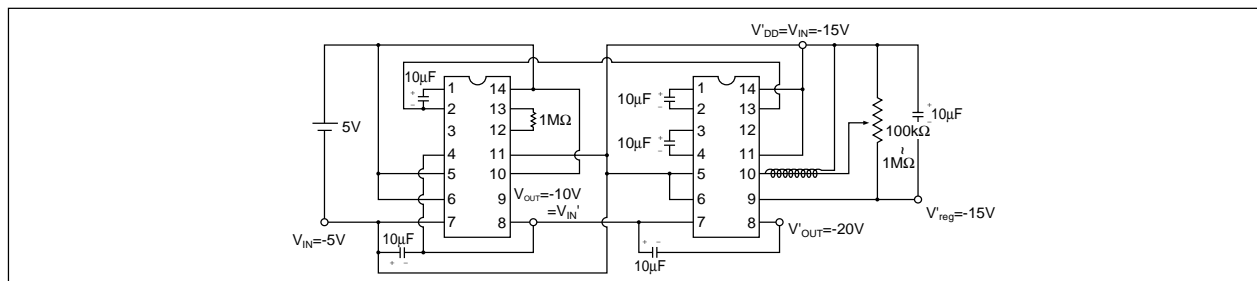
In parallelly connection, a regulated output can be obtained by applying the regulation circuit to only one of the n parallelly connected circuit.



Parallel Connection

● Cascade Connection

Cascade connection of SCI7661C/M (by connecting V_{IN} and V_{OUT} of one stage to V_{DD} and V_{IN} respectively of the next stage) further increase the output voltage. Note, however, that the serial connection increases the output impedance.

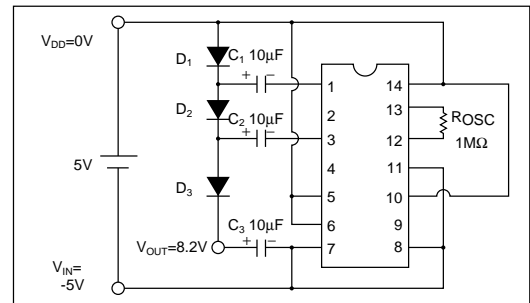


Serial Connection

● Positive Voltage Conversion

The input voltage can be doubled or tripled toward the positive side. (In the doubler configuration, capacitor C_2 and diode D_3 are disconnected and the diode D_3 shorted at the both ends.) In this case, however, the output voltage decrease by V_F (forward voltage)

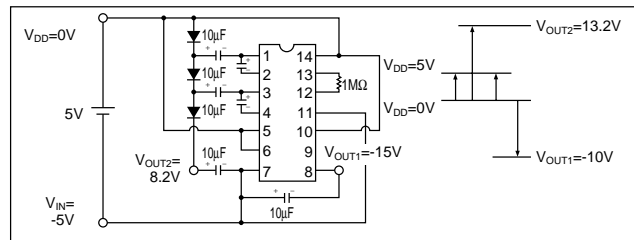
For example $V_{DD}=0V$, $V_{IN}=-5V$ and $V_F=0.6V$, then $V_{OUT}=10V-3 \times 0.6V=8.2V$ (if doubled, $5V-2 \times 0.6V=3.8V$)



Positive Voltage Conversion D_1, D_2, D_3 .: Shottky diodes with small V_F are recommended.

● Negative Voltage Conversion + Positive Voltage Conversion

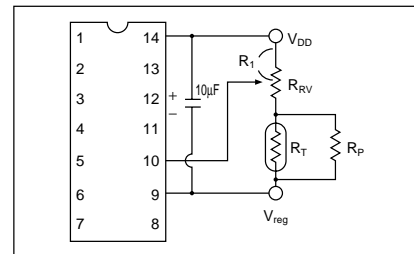
This circuit produces outputs of $-15V$ and $+8.2V$ from the $-5V$ input. Note that this configuration causes higher output impedance than in a single function (negative or positive voltage converter).



Negative Voltage Conversion +Positive Voltage Conversion

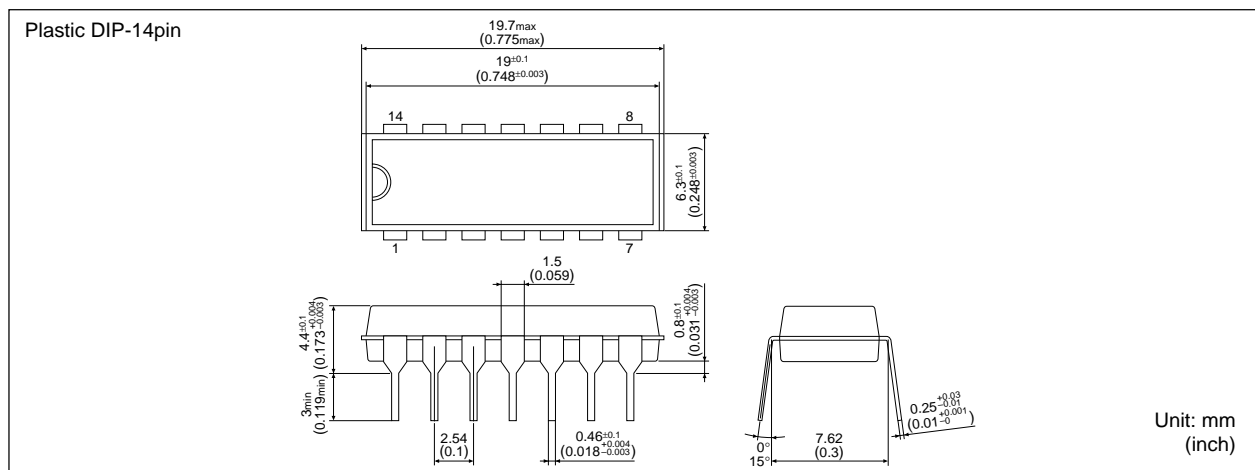
● Changing the Temperature Gradient through Use of External Temperature Sensor (Thermistor)

The SCI7661C/M has a temperature gradient selector circuit in its regulator. It selects any one of the three gradients: $-0.1\% / ^\circ C$, $-0.4\% / ^\circ C$ and $-0.6\% / ^\circ C$. It is necessary that the temperature gradient can be changed to any other value by connecting a thermistor in series to the output voltage control resistor R_{RV} .

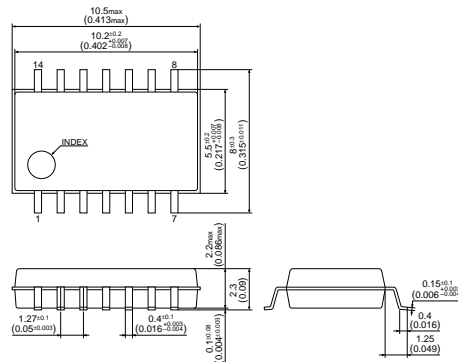


Example of Change of Temperature Gradient

■ PACKAGE DIMENSIONS



Plastic SOP5-14pin



Unit: mm
(inch)

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